

# isc N-Channel MOSFET Transistor

## APT12M80B

#### **FEATURES**

- Drain Current -I<sub>D</sub>=13A@ T<sub>C</sub>=25°C
- · Drain Source Voltage-
  - : V<sub>DSS</sub>=800V(Min)
- · Static Drain-Source On-Resistance
  - :  $R_{DS(on)}$  = 0.8  $\Omega$  (Max)
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



### **DESCRIPTION**

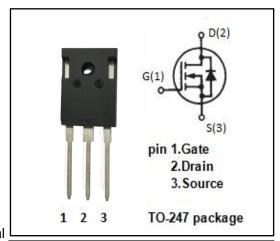
 Designed for use in switch mode power supplies and general purpose applications.

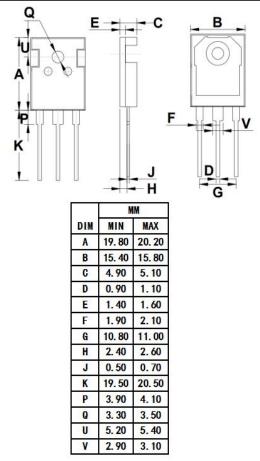
### ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>DSS</sub>	Drain-Source Voltage	800	V
V <sub>GS</sub>	Gate-Source Voltage-Continuous	±30	V
I <sub>D</sub>	Drain Current-Continuous	13	А
I <sub>DM</sub>	Drain Current-Single Pluse	45	А
P <sub>D</sub>	Total Dissipation @T <sub>C</sub> =25℃	335	W
TJ	Max. Operating Junction Temperature -55~150		°C
T <sub>stg</sub>	Storage Temperature -55~150		$^{\circ}$ C

### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R <sub>th j-c</sub>	Thermal Resistance, Junction to Case	0.37	°C/W







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#### **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
V <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0; I <sub>D</sub> = 0.25mA	800		V
V <sub>GS(th)</sub>	Gate Threshold Voltage	$V_{DS}$ = $V_{GS}$ ; $I_D$ = 1mA	3	5	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> =6A		0.8	Ω
Igss	Gate-Body Leakage Current	V <sub>GS</sub> = ±30V;V <sub>DS</sub> = 0		±100	nA
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 800V; V <sub>GS</sub> = 0 V <sub>DS</sub> = 800V; V <sub>GS</sub> = 0@T <sub>J</sub> =125℃		100 500	μА
V <sub>SD</sub>	Forward On-Voltage	I <sub>S</sub> =-6A; V <sub>GS</sub> = 0		1	V

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